

650 nm LASER DIODE

Features

- "Visible wavelength: 650 nm (typ.)
- "Optical power: 5 mW (CW)
- "TO-18 package with flat window (ø 5.6 mm)
- "Low operating current: lop = 33 mA (typ.)
- "Low operating voltage: Vop = 2.8 V (max)

Recommended operating optical power output

"Less than 5 m W

Applications

"Laser pointers

- "Laser modules
- "Bar code readers

Structure

Index-guided structure AlGaInP quantum well structure Integrated Si photodiode for optical power monitor



Description

The MCE-6E8F-Z02 is a red laser diode typically powered at 3 to 5 mW and designed for laser pointer.

The device contains a PIN photo diode to meet the designs of the automatic-power-control circuit. The small TO-18 package and lower consumption enable customers to easily incorporate our laser diodes into their products.

Handling and Safety Precautions

Anti-static protection, such as ionized air blowers or grounded wrist straps with a 1 mega series resistor, should be used at all times when handling laser diodes. In addition, soldering irons should be well grounded.

Overheating caused by soldering of the leads of a laser diode must be prevented. Recommend soldering iron temperature and maximum exposure time are below 260 $^{\circ}$ C and 10 seconds.

Unity Opto Technology Co., Ltd. 10 F, No. 88-8, Sec. 1, Kuang-Fu Rd., Sanchung City, 241 Taipei, Taiwan **For prototype and Production call** TEL: 886 - 2 -2999 - 3988 FAX: 886 - 2 -2999 - 3910 REV. A 09/11/2002

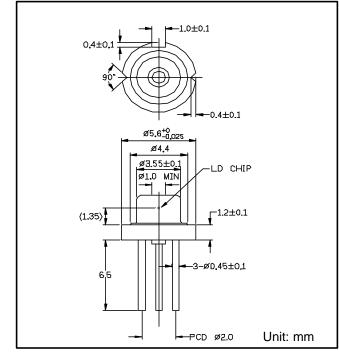


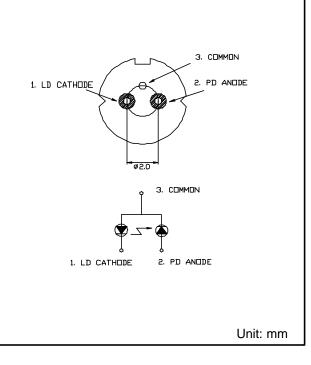
Absolute Maximum Ratings (Ta: 25°C)

PARAMETERS	SYMBOL	Rated Value		
Storage Temperature	Tstg	-20 to +85		
Operating Temperature	Тор	-10 to + 40		
Optical output power (m W)	Ро	7		
LD reverse voltage (V)	Vr(LD)	2		
PD reverse voltage (V)	Vr (PD)	30		

■ Optical & Electrical Characteristics (Ta = 25°C)

Parameter	r	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Optical outp	out power	Ро	Kink free,CW	3⁄4	3⁄4	5	mW
Threshold c	urrent	lth		3⁄4	24	35	mA
Operating c	ureent	Іор	Po=5mW	3⁄4	33	40	mA
Operatign v	oltage	Vop	Po=5mW	3⁄4	2.2	2.8	V
Wavelength		lp	Po=5mW	3⁄4	650	660	nm
Beam	Perpendicular	Ŧ	Po=5mW	3⁄4	29	3⁄4	deg
divergence	Parallel	¶/	Po=5mW	3⁄4	8	3⁄4	deg
Slope efficiency		h	2mW [IF(5mW)-IF(3mW)]	3⁄4	0.6	3⁄4	mW/mA
Monitor current		Im	Po=5mW, Vr=5V	3⁄4	350	3⁄4	ìΑ





Package Dimensions

NOTE: Specifications are subjected to change without notice.

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Pin Connections (Bottom View)

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